









	STB13N60M2	
	Hersteller-Teilenummer:	STB13N60M2
	Hersteller / Marke:	STMicroelectronics
	Teil der Beschreibung:	MOSFET N-CH 600V 11A D2PAK
	Datenblätter:	 STB13N60M2.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 73380 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	STB13N60M2
Hersteller	STMicroelectronics
Beschreibung	MOSFET N-CH 600V 11A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	73380 pcs Stock
Serie	MDmesh™ II Plus
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D2PAK
Verlustleistung (max)	110W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	11A (Tc)
Rds On (Max) @ Id, Vgs	380 mOhm @ 5.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	580pF @ 100V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tape & Reel (TR)



















































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Anfrage STB13N60M2: Info@Y-IC.com

Sie können auch interessiert sein:

 STB13005-1 STMicroelectronics TRANS NPN 400V 4A I2PAK	 STB13NK60Z-1 ST STB13NK60Z-1 ST	 STB13NM50N-1 STMicroelectronics MOSFET N-CH 500V 12A I2PAK	 STB130NH02LT4 ST STB130NH02LT4 ST
 STB13NK60ZT4 STMicroelectronics MOSFET N-CH 600V 13A D2PAK	 STB13N80K5 STMicroelectronics MOSFET N-CH 800V 12A D2PAK	 STB13NM50N STMicroelectronics MOSFET N-CH 500V 12A D2PAK	 STB130NS04ZBT4 STMicroelectronics MOSFET N-CH 33V 80A D2PAK

heiße Teile

Mehr

 STB11NK40ZT4	 STB11NK50ZT4	 STB11NM60	 D STB11NM60-1	 STB11NM60A-1
 STB11NM60FDT4	 STB11NM60T4	 D STB11NM80	 STB11NM80T4	 STB120N4F6
 STB120N4LF6	 STB120NF10	 STB120NF10T4	 STB120NH03LT4	 STB1277-Y
 D STB1277LY-AT	 STB12NK80Z	 STB12NK80Z-1	 STB12NM50	 STB12NM50FD-1
 STB12NM50ND	 STB12NM50T4	 STB13005-1	 STB130NH02LT4	 STB130NS04ZBT4
 STB13NK60Z-1	 STB13NK60ZT4	 D STB13NM50N-1	 STB13NM50NT4	 STB13NM60NT4
 STB140NF55	 D STB140NF55T4	 STB140NF75	 STB140NF75T4	 STB14NF10T4
 STB14NK50Z	 STB14NK50Z-1	 STB14NK50ZT4	 STB14NK60Z	 STB14NK60ZT4
 STB14NM50N	 STB150N3LH6	 STB150NF04	 D STB150NF55	 STB150NF55T4
 STB155N3LH6	 STB15N65M5	 STB15N80K5	 STB15NK50Z	 STB15NK50Z-1

Contact us: Info@Y-IC.com

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